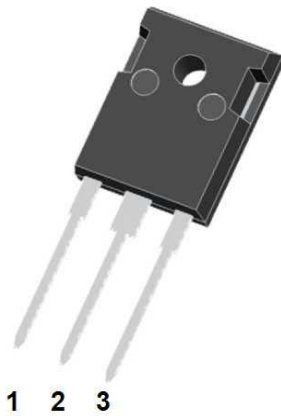


Schottky Barrier Rectifiers



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-247AB
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■ Maximum Ratings (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR40100PT	MBR40150PT	MBR40200PT
Device marking code			MBR40100PT	MBR40150PT	MBR40200PT
Repetitive peak reverse voltage	VRRM	V	100	150	200
Average Rectified Forward Current (Rated VR-20Khz Square Wave) - 50% duty cycle, T _c (FIG 1)	IFAV	A	40		
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _j =25°C	IFSM	A	300		
Current Squared Time @1ms≤t≤8.3ms T _j =25°C	I ² t	A ² s	373		
Storage temperature	TSTG	°C	-55 ~+175		
Junction temperature	TJ	°C	-55 ~+175		

■ Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR40100PT	MBR40150PT	MBR40200PT
Maximum instantaneous forward voltage drop per diode	V _F	V	I _F =20A, T _J =25°C	0.85	0.85	0.9
Maximum DC reverse current at rated DC blocking voltage per diode @ VRM=VRRM	I _{RRM}	mA	VRM=VRRM T _J =25°C	0.1		
			VRM=VRRM T _J =125°C	20		

■ Thermal Characteristics (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR40100PT	MBR40150PT	MBR40200PT
Typical Thermal Resistance(Per leg)	R _{θJ-C}	°C/W	1.0		



MBR40100PT THRU MBR40200PT

Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR40100PT THUR MBR40200PT	Approximate 6.0	30	330	1980	Tube

Characteristics(Typical)

FIG1:Io -Tc Curve

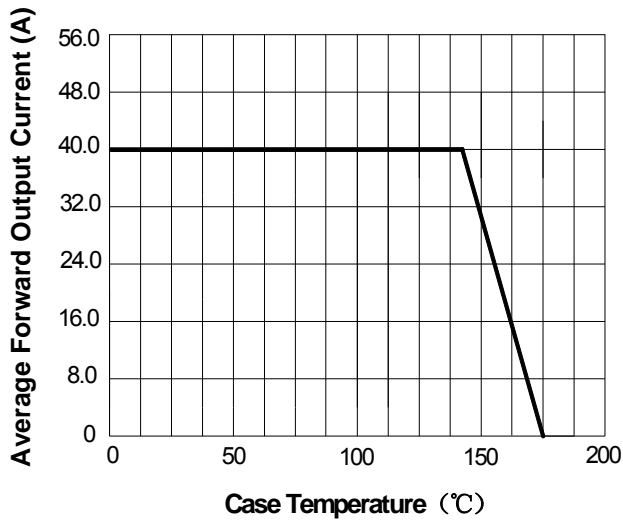


FIG2:Surge Forward Current Capability

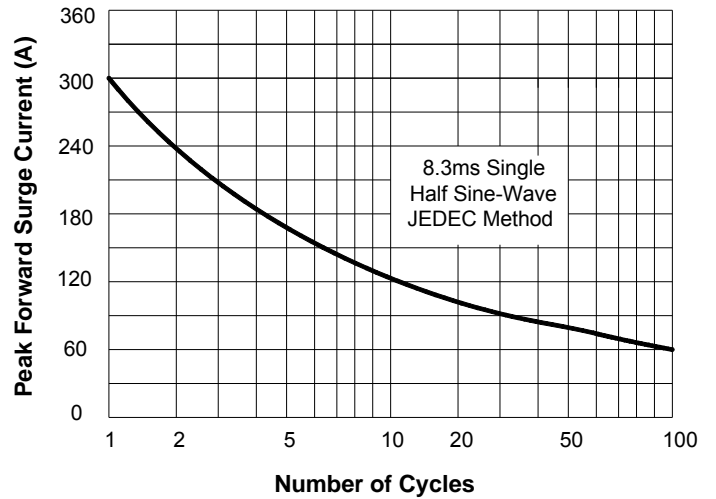


FIG3: Forward Voltage

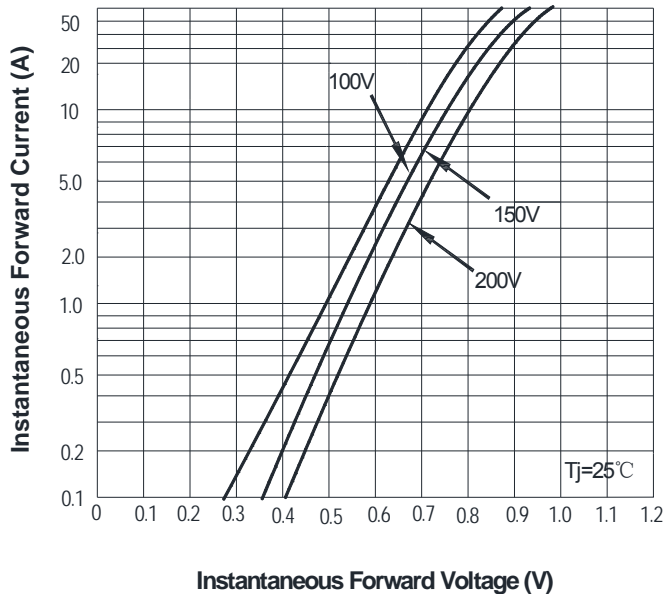
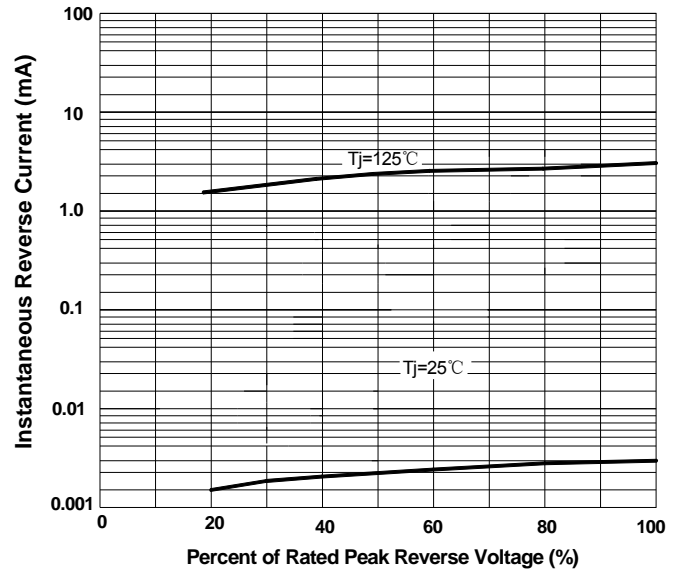


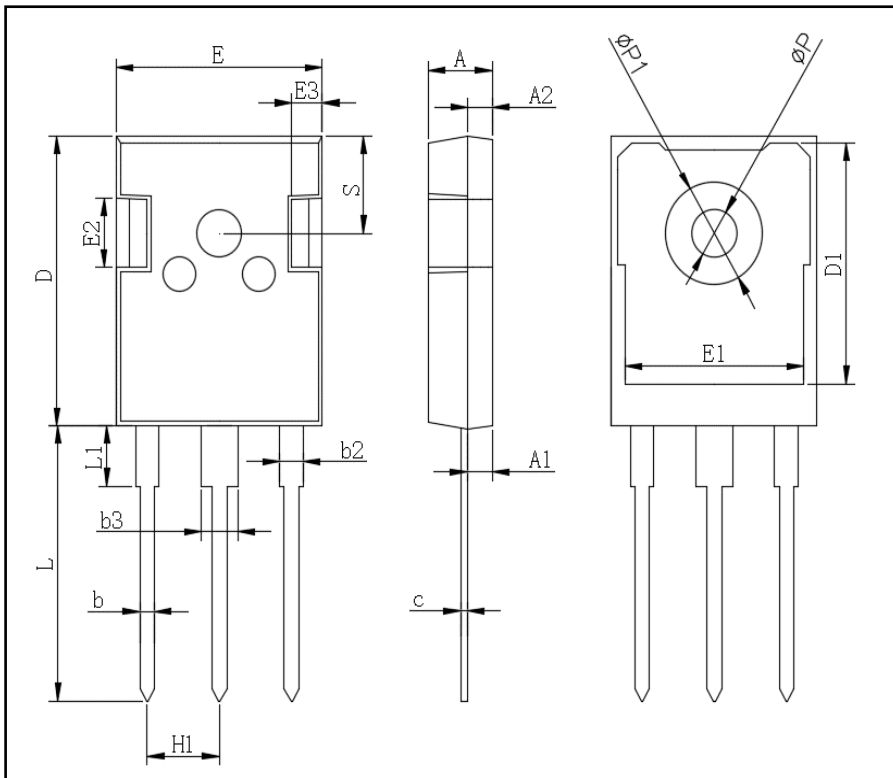
FIG.4: Instantaneous Reverse Characteristics





MBR40100PT THRU MBR40200PT

■ Outline Dimensions



TO-247AB		
Dim	Min	Max
A	4.80	5.20
A1	2.21	2.61
A2	1.85	2.15
b	1.0	1.4
b2	1.91	2.21
C	0.5	0.7
D	20.70	21.30
D1	16.25	16.85
E	15.50	16.10
E1	13.0	13.6
E2	4.80	5.20
E3	2.30	2.70
L	19.62	20.22
L1	-	4.30
ΦP	3.40	3.80
ΦP1		7.30
S	6.15TYP	
H1	5.44TYP	
b3	2.80	3.20



MBR40100PT THRU MBR40200PT

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